

MIC5841/5842

8-Bit Serial-Input Latched Drivers

General Description

Using BiCMOS technology, the MIC5841/5842 integrated circuits were fabricated to be used in a wide variety of peripheral power driver applications. The devices each have an eight-bit CMOS shift register, CMOS control circuitry, eight CMOS data latches, and eight bipolar current-sink Darlington output drivers.

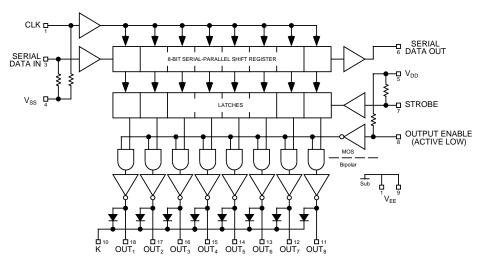
These two devices differ only in maximum voltage ratings. The MIC5842 offers premium performance with a minimum output breakdown voltage rating of 80V (50V sustaining). The drivers can be operated with a split supply where the negative supply is down to -20V.

The 500 mA outputs, with integral transient-suppression diodes, are suitable for use with lamps, relays, solenoids and other inductive loads.

These devices have improved speed characteristics. With a 5V logic supply, they will typically operate faster than 5 MHz. With a 12V supply, significantly higher speeds are obtained. The CMOS inputs are compatible with standard CMOS, PMOS, and NMOS logic levels. TTL or DTL circuits may require the use of appropriate pull-up resistors. By using the serial data output, the drivers can be cascaded for interface applications requiring additional drive lines.

The MIC5840 family is available in DIP, PLCC, and SOIC packages. Because of limitations on package power dissipation, the simultaneous operation of all drivers at maximum rated current might require a reduction in duty cycle. A copper-alloy lead frame provides for maximum package power dissipation.

Functional Diagram



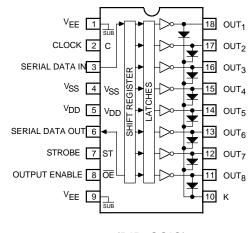
Features

- 3.3 MHz Minimum Data-Input Rate
- CMOS, PMOS, NMOS, TTL Compatible
- Internal Pull-Up/Pull-Down Resistors
- Low-Power CMOS Logic and Latches
- High-Voltage Current-Sink Outputs
- Output Transient-Protection Diodes
- Single or Split Supply Operation

Ordering Information

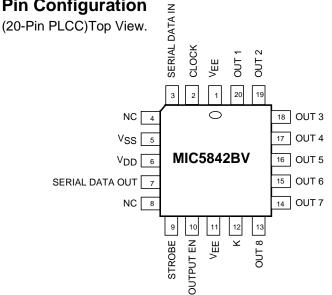
Part Number	Temperature Range	Package
MIC5841BN	–40°C to +85°C	18-Pin Plastic DIP
MIC5841BV	–40°C to +85°C	20-Pin PLCC
MIC5841BWM	–40°C to +85°C	18-Pin Wide SOIC
MIC5842BN	–40°C to +85°C	18-Pin Plastic DIP
MIC5842BV	–40°C to +85°C	20-Pin PLCC
MIC5842BWM	–40°C to +85°C	18-Pin Wide SOIC

Pin Configuration



(DIP, SOIC)

Pin Configuration



Absolute Maximum Ratings (Note 1, 2, 3)

at 25°C Free-Air Temperature and $V_{SS} = 0V$

Output Voltage, V _{CE} (MIC5841)	50V
(MIC5842)	80V
Output Voltage, VCE(SUS) (MIC5841) (Note	e 1) 35V
(MIC5842)	50V
Logic Supply Voltage, V _{DD}	15V
V _{DD} with Reference to V _{EE}	25V
Emitter Supply Voltage, V _{EE}	–20V
Input Voltage Range, V _{IN}	-0.3V to V _{DD} + 0.3V
Continuous Output Current, IOUT	500mA
Package Power Dissipation, PD (Note 2)	1.82W
Operating Temperature Range, T _A	–55°C to +85°C
Storage Temperature Range, T _S	–65°C to +150°C

Note 1: For Inductive load applications.

Note 2: Derate at the rate of $18.2 \text{mW/}^{\circ}\text{C}$ above $T_{\text{A}} = 25^{\circ}\text{C}$ (Plastic DIP) Note 3: CMOS devices have input-static protection but are susceptible to damage when exposed to extremely high static electrical charges.

Electrical Characteristics at $T_A = 25^{\circ}C V_{DD} = 5V$, $V_{SS} = V_{EE} = 0V$ (unless otherwise noted)

		Applicable			Limits	_	
Characteristic	Symbol	Devices	Test Conditions	Min.	Max.	Unit	
Output Leakage Current	ICEX	MIC5841	$V_{OUT} = 50V$		50	μA	
			$V_{OUT} = 50V, T_A = +70^{\circ}C$		100		
		MIC5842	$V_{OUT} = 80V$		50]	
			$V_{OUT} = 80V, T_{A} = +70^{\circ}C$		100		
Collector-Emitter	V _{CE(SAT)}	Both	I _{OUT} = 100mA		1.1	V	
Saturation Voltage			I _{OUT} = 200mA		1.3]	
			I _{OUT} = 350mA, V _{DD} = 7.0V		1.6		
Collector-Emitter	V _{CE(SUS)}	MIC5841	I _{OUT} = 350mA, L = 2mH	35		V	
Sustaining Voltage (Note 5)		MIC5842	I _{OUT} = 350mA, L = 2mH	50			
Input Voltage	V _{IN(0)}	Both			0.8	V	
	V _{IN(1)}	Both	V _{DD} = 12V	10.5			
			V _{DD} = 10V	8.5			
			V _{DD} = 5.0V (See Note 4)	3.5			
Input Resistance	R _{IN}	Both	V _{DD} = 12V	50		kΩ	
			V _{DD} = 10V	50			
			$V_{DD} = 5.0V$	50			
Supply Current	I _{DD(ON)}	Both	All Drivers ON, V _{DD} = 12V		16	mA	
			All Drivers ON, V _{DD} = 10V		14		
			All Drivers ON, V _{DD} = 5.0V		8.0]	
	IDD(OFF)	Both	All Drivers OFF, V _{DD} = 12V		2.9		
			All Drivers OFF, V _{DD} = 10V		2.5		
			All Drivers OFF, $V_{DD} = 5.0V$		1.6		
Clamp Diode	I _R	MIC5841	V _R = 50V		50	μA	
Leakage Current MIC5842		MIC5842	V _R = 80V	50		7	
Clamp Diode Forward Voltage	VF	Both	I _F = 350mA		2.0	V	

Note 4: Operation of these devices with standard TTL may require the use of appropriate pull-up resistors to insure an input logic HIGH.

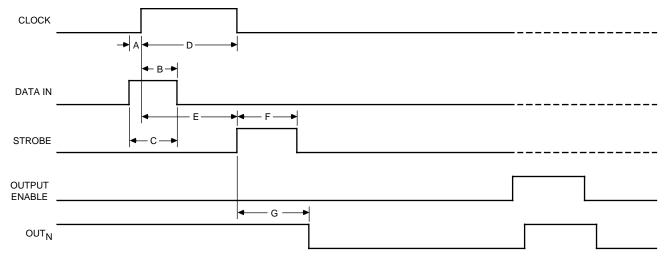
Note 5: Not 100% tested. Guaranteed by design.

				Limits	
Characteristic	Symbol	Test Conditions	Min.	Max.	Unit
Output Leakage Current	ICEX	V _{OUT} = 80V		50	μA
Collector-Emitter	V _{CE(SAT)}	I _{OUT} = 100mA		1.3	V
Saturation Voltage		I _{OUT} = 200mA		1.5	
		I _{OUT} = 350mA, V _{DD} = 7.0V		1.8	1
Input Voltage	V _{IN(0)}			0.8	V
	V _{IN(1)}	V _{DD} = 12V	10.5		1
		V _{DD} = 5.0V	3.5		1
Input Resistance	R _{IN}	V _{DD} = 12V	35		kΩ
		V _{DD} = 10V	35		1
		V _{DD} = 5.0V	35		1
Supply Current	I _{DD(ON)}	All Drivers ON, V _{DD} = 12V		16	mA
		All Drivers ON, V _{DD} = 10V		14	
		All Drivers ON, V _{DD} = 5.0V		10	1
	IDD(OFF)	All Drivers OFF, V _{DD} = 12V		3.5	1
		All Drivers OFF, V _{DD} = 5.0V		2.0	1

Electrical Characteristics $T_A = -55^{\circ}C$, $V_{DD} = 5V$, $V_{SS} = V_{EE} = 0V$ (unless otherwise noted)

Electrical Characteristics $T_A = +125^{\circ}C$, $V_{DD} = 5V$, $V_{SS} = V_{EE} = 0V$ (unless otherwise noted)

					Limits		
Characteristic	Symbol	Test Conditions	;	Min.	Max.	Unit	
Output Leakage Current	ICEX			500	μΑ		
Collector-Emitter	V _{CE(SAT)}		I _{OUT} = 100mA		1.3	V	
Saturation Voltage			I _{OUT} = 200mA		1.5		
			I _{OUT} = 350mA, V _{DD} = 7.0V		1.8		
Input Voltage	V _{IN(0)}				0.8	V	
	VIN(1)		V _{DD} = 12V	10.5			
			$V_{DD} = 5.0V$	3.5			
Input Resistance	R _{IN}		V _{DD} = 12V			kΩ	
			V _{DD} = 10V	50			
			V _{DD} = 5.0V	50			
Supply Current	I _{DD(ON)}		All Drivers ON, V _{DD} = 12V		16	mA	
			All Drivers ON, V _{DD} = 10V		14		
			All Drivers ON, $V_{DD} = 5.0V$		8		
	IDD(OFF)		All Drivers OFF, V _{DD} = 12V		2.9		
			All Drivers OFF, $V_{DD} = 5.0V$		1.6	1	
Clamp Diode Leakage	I _R	MIC5841A	V _R = 50V		100	μΑ	
Current		MIC5842A	V _R = 80V		100		



Timing Conditions

(1)	$_{A}$ = 25°C Logic Levels are V _{DD} and V _{SS})	$V_{DD} = 5V$
A.	Minimum Data Active Time Before Clock Pulse (Data Set-Up Time)	75 ns
	Minimum Data Active Time After Clock Pulse (Data Hold Time)	
C.	Minimum Data Pulse Width	150 ns
D.	Minimum Clock Pulse Width	150 ns
E.	Minimum Time Between Clock Activation and Strobe	300 ns
F.	Minimum Strobe Pulse Width	100 ns
G.	. Typical Time Between Strobe Activation and Output Transition	500 ns

SERIAL DATA present at the input is transferred to the shift register on the logic "0" to logic "1" transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUTPUT. The SERIAL DATA must appear at the input prior to the rising edge of the CLOCK input waveform.

Information present at any register is transferred to its respective latch when the STROBE is high (serial-to-parallel conversion). The latches will continue to accept new data as long as the STROBE is held high. Applications where the latches are bypassed (STROBE tied high) will require that the ENABLE input be high during serial data entry.

When the ENABLE input is high, all of the output buffers are disabled (OFF) without affecting information stored in the latches or shift register. With the ENABLE input low, the outputs are controlled by the state of the latches.

Serial		Shi	ft Reg	jister	Conte	ents	Serial	Serial Latch Contents					Output Contents						
Data Input	Clock Input	I ₁	I ₂	I ₃		I ₈	Data Output	Strobe Input	I ₁	l ₂	l ₃		I ₈	Output Enable	I ₁	l ₂	l3		I ₈
Н		Н	R ₁	R_2		R ₇	R ₇												
L		L	R ₁	R_2		R ₇	R ₇												
Х		R ₁	R_2	R_3		R ₈	R ₈												
		Х	Х	Х		Х	Х	L	R ₁	R_2	R_3		R ₈						
		Р ₁	P ₂	P ₃		P ₈	P ₈	Н	P ₁	P ₂	P ₃		P ₈	L	P ₁	P ₂	P ₃		P ₈
									Х	Х	Х		Х	Н	Н	Н	Н		Н

MIC5840 Family Truth Table

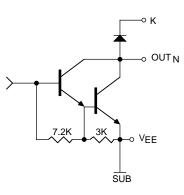
L = Low Logic Level

H = High Logic Level

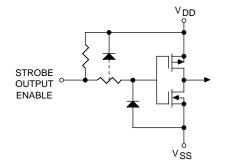
X = Irrelevant

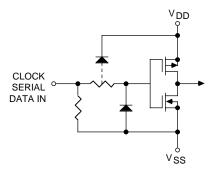
P = Present State

R = Previous State









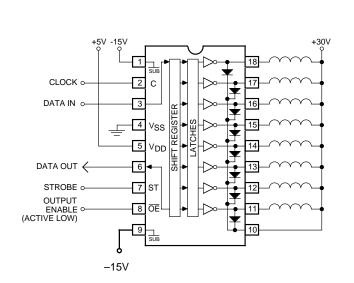
Maximum Allowable Duty Cycle (Plastic DIP) $V_{DD} = 5.0V$

Number of Outputs ON (I _{OUT} = 200mA	Ma	x. Allowable D	uty Cycle at An	nbient Tempe	rature of
V _{DD} = 5.0V)	25°C	40°C	50°C	60°C	70°C
8	85%	72%	64%	55%	46%
7	97%	82%	73%	63%	53%
6	100%	96%	85%	73%	62%
5	100%	100%	100%	88%	75%
4	100%	100%	100%	100%	93%
3	100%	100%	100%	100%	100%
2	100%	100%	100%	100%	100%
1	100%	100%	100%	100%	100%

$V_{DD} = 12V$

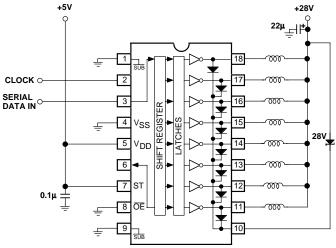
Number of Outputs ON (I _{OUT} = 200mA	Max. /	Allowable Duty	Cycle at Ambi	ent Temperati	ure of
V _{DD} = 12V)	25°C	40°C	50°C	60°C	70°C
8	80%	68%	60%	52%	44%
7	91%	77%	68%	59%	50%
6	100%	90%	79%	69%	58%
5	100%	100%	95%	82%	69%
4	100%	100%	100%	100%	86%
3	100%	100%	100%	100%	100%
2	100%	100%	100%	100%	100%
1	100%	100%	100%	100%	100%

Typical Applications



Relay/Solenoid Driver

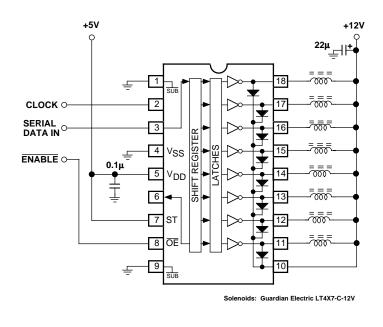
MIC5842

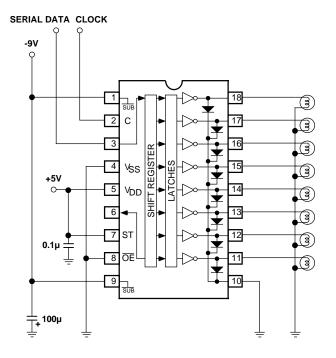


MIC5841 Hammer Driver

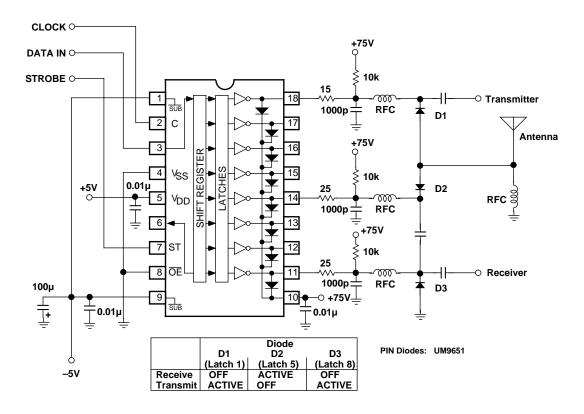
MIC5841 Solenoid Driver with Output Enable

MIC5841 Level Shifting Lamp Driver with Darlington Emitters Tied to a Negative Supply





Typical Applications, Continued



MIC5842 Negative/Positive Supply PIN Diode Driver Transmit/Receive Switch